Lead (Pb) Free Product - RoHS Compliant

LED970-xx

Infrared LED Lamp

LED970-xx is an GaAs LED mounted on a lead frame and encapsulated in various types of epoxy lens which offer different design settings.

On forward bias, it emits a high power radiation of typical 8mW with a peak wavelenth at 970nm.

• Specifications

Chip material GaAs
Peak wavelength 970nm

3) Package Clear epoxy resin

4) Lead frame Soldered



• Absolute Maximum Ratings

Item	Symbol	Maximum Rated Value	Unit	Ambient Temperature
Power Dissipation	Pb	140	mW	Ta=25°C
Forward Current	lf	100	mA	Ta=25°C
Pulse Forward Current	lfp	1000	mA	Ta=25°C
Reverse Voltage	VR	5	V	Ta=25°C
Operating Temperature	Topr	-30 ~ +85	°C	
Storage Temperature	Тsтg	-30 ~ +100	°C	
Soldering Temperature	Tsol	260	°C	

• Electro-Optical Characteristics [Ta=25°C]

Item	Symbol	Condition	Minimum	Typical	Maximum	Unit
Forward Voltage	VF	I=50mA		1.30	1.45	V
Reverse Current	lr	Vr=5V			10	uA
Radiated Power	Po	I==50mA	4.0	8.0		mW
Peak Wavelength	λР	I==50mA		970		nm
Half Width	Δλ	I==50mA		55		nm
Rise Time	tr	I==50mA		1000		ns
Fall Time	tf	I==50mA		500		ns

• Characteristics of Radiant Intensity [Ta=25°C]

Туре	Viewing Half Angle	Radiant Intensity IF= 50mA [mW/sr]			Outer Dimension	
		Minimum	Typical	Maximum	Dimension	Figure
LED970-01	± 10°		13		Ø 5	1
LED970-02	±5°		16		Ø 5	2
LED970-03	± 15°		11		Ø 5	3
LED970-04	± 20°		5		Ø 5	4
LED970-05	± 40°		1		Ø 5	5
LED970-06	± 7°		20		Ø 5	6
LED970-09	± 25° (Long)				Ø 5	7
	± 15° (Short)		8		Oval	
LED970-31					Ø 3	8
LED970-33	± 15°		5		Ø 3	9
LED970-34					Ø 3	10
LED970-36	± 30°		2.5		Ø 3	11
LED970-41					Ø 4	12
LED970-42					Ø 4	12

[▶] Radiated Intensity is measured by Tektronix J-16.

[►] Total Radiated Power is measured by #500.